

20 V, 1.2 A P-channel Trench MOSFET Rev. 2 — 6 December 2011

Product data sheet

Product profile 1.

1.1 General description

P-channel enhancement mode Field-Effect Transistor (FET) in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- 1.8 V R_{DSon} rated
- Very fast switching

1.3 Applications

- Relay driver
- High-speed line driver

- Trench MOSFET technology
- High-side loadswitch
- Switching circuits

1.4 Quick reference data

Table 1.	Quick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V_{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} 25 °C	<u>[1]</u>	-	-	-1.2	А
Static cha	aracteristics						
R_{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I _D = -1.2 A; T _j = 25 °C		-	170	210	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

Pinning information 2.

1.1

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		-
2	S	source		
3	D	drain		G (F)
			SOT23 (TO-236AB)	S 017aaa257



3. Ordering information

Version
SOT23

4. Marking

Table 4.Marking codes

Type number	Marking code ^[1]
PMV160UP	NH%

[1] % = placeholder for manufacturing site code

5. Limiting values

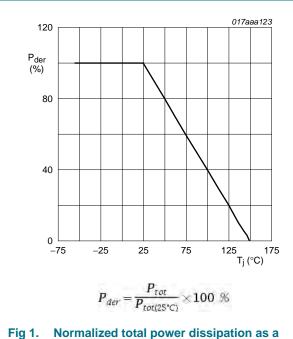
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

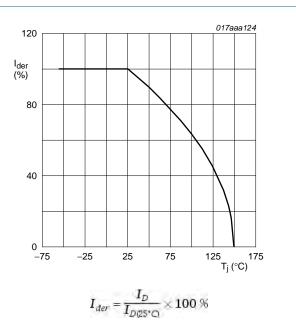
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} 25 °C	<u>[1]</u>	-	-1.2	А
		V_{GS} = -4.5 V; T_{amb} = 100 °C	<u>[1]</u>	-	-0.8	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-4	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	335	mW
			[1]	-	480	mW
		T _{sp} = 25 °C		-	2170	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode					
I _S	source current	T _{amb} = 25 °C	<u>[1]</u>	-	-0.5	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



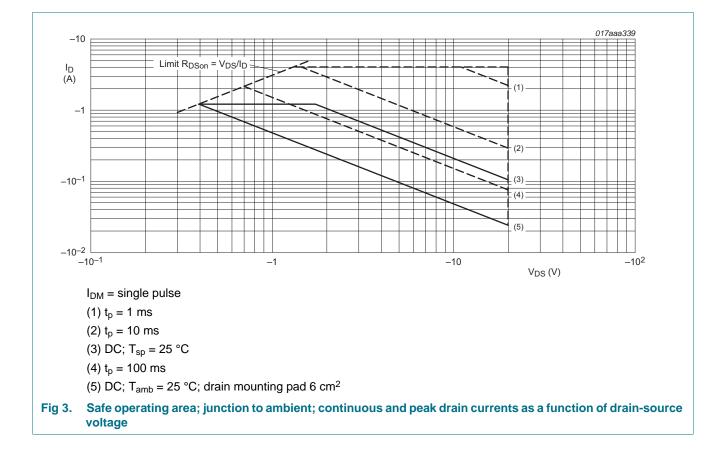
function of junction temperature





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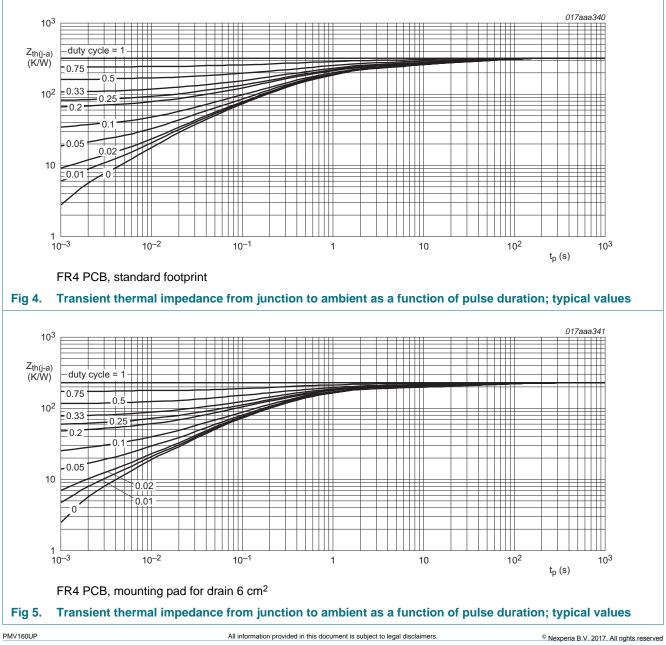


6. Thermal characteristics

Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	<u>[1]</u>	-	325	374	K/W
	from junction to ambient		[2]	-	227	260	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	50	60	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

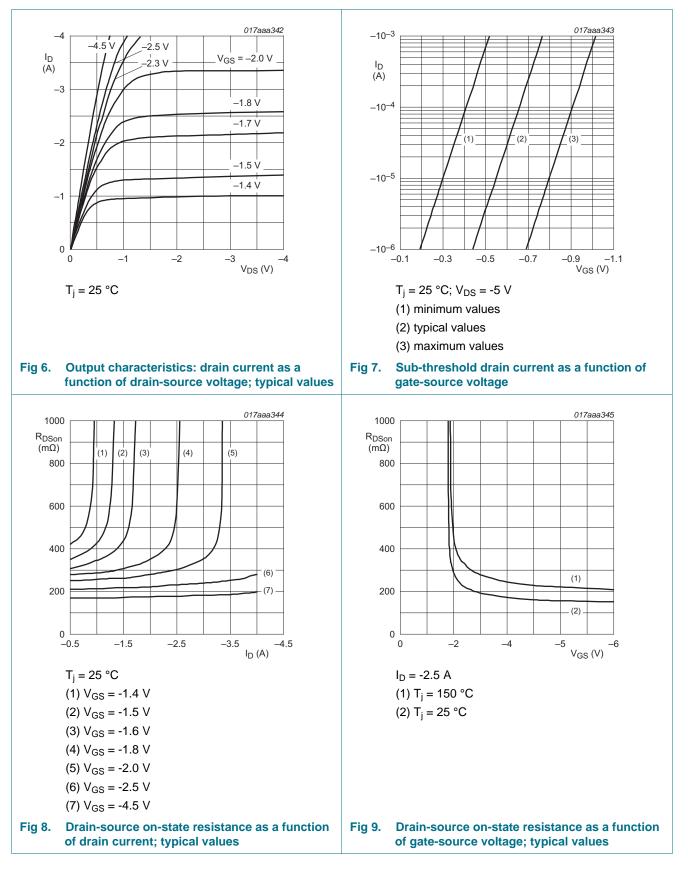


7. Characteristics

Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-0.45	-0.7	-0.95	V
I _{DSS}	drain leakage current	V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
		$V_{DS} = -20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ °C}$	-	-	-10	μA
I _{GSS}	gate leakage current	$V_{GS} = -8 \text{ V}; V_{DS} = 0 \text{ V}; \text{ T}_{j} = 25 \text{ °C}$	-	-	-100	nA
		$V_{GS} = 8 \text{ V}; V_{DS} = 0 \text{ V}; \text{T}_{j} = 25 ^{\circ}\text{C}$	-	-	-100	nA
R _{DSon}	drain-source on-state	V_{GS} = -4.5 V; I _D = -1.2 A; T _j = 25 °C	-	170	210	mΩ
	resistance	V_{GS} = -4.5 V; I _D = -1.2 A; T _j = 150 °C	-	- 265	328	mΩ
		V_{GS} = -2.5 V; I _D = -1.1 A; T _j = 25 °C	- 210	270	mΩ	
		V_{GS} = -1.8 V; I _D = -0.5 A; T _j = 25 °C	-	280	380	mΩ
9 _{fs}	forward transconductance	$V_{DS} = -5 \text{ V}; \text{ I}_{D} = -1.2 \text{ A}; \text{ T}_{j} = 25 \text{ °C}$	-	3.7	-	S
Dynamic o	characteristics					
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I_{D} = -1 A; V_{GS} = -4.5 V;	-	3.3	4	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1	-	nC
Q _{GD}	gate-drain charge		-	0.5	-	nC
C _{iss}	input capacitance	V_{DS} = -10 V; f = 1 MHz; V_{GS} = 0 V;	-	365	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	42	-	pF
C _{rss}	reverse transfer capacitance		-	30	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; V_{GS} = -4.5 V; $R_{G(ext)}$ = 6 Ω ;	-	7	-	ns
t _r	rise time	T _j = 25 °C; I _D = -1 A	-	26	-	ns
t _{d(off)}	turn-off delay time		-	35	-	ns
t _f	fall time		-	17	-	ns
Source-dr	ain diode					
V _{SD}	source-drain voltage	I _S = -0.5 A; V _{GS} = 0 V; T _i = 25 °C	-	-0.7	-1.2	V

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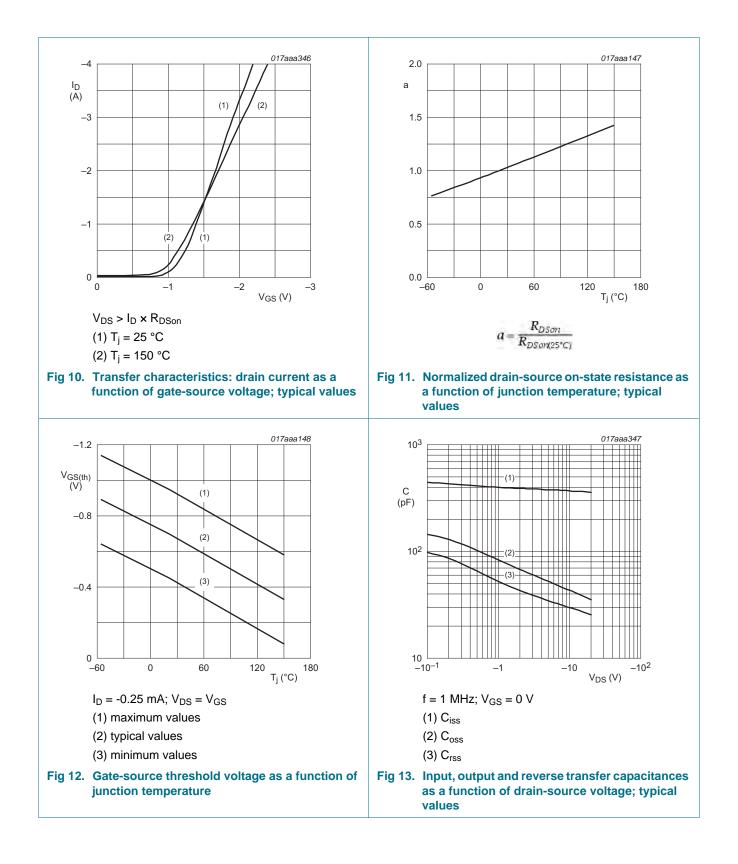
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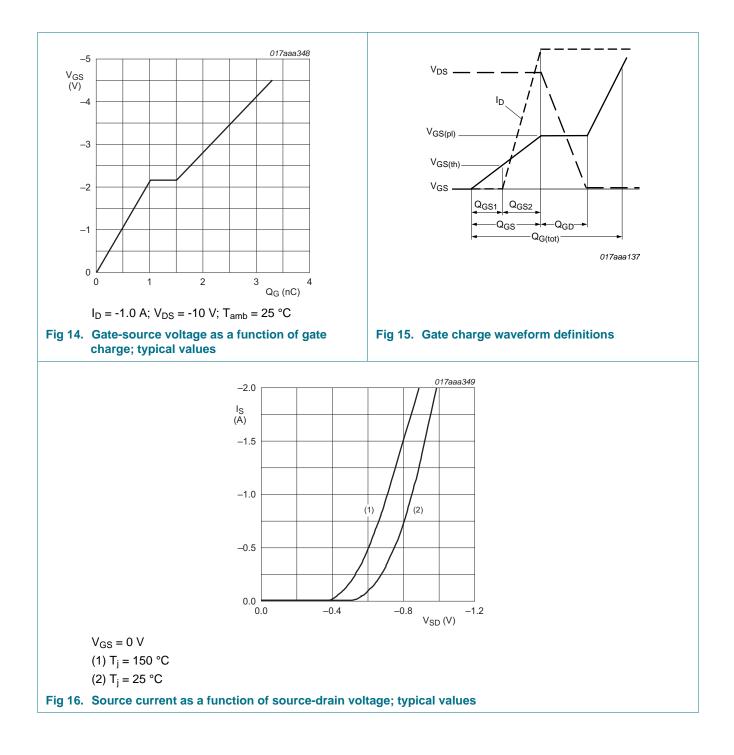
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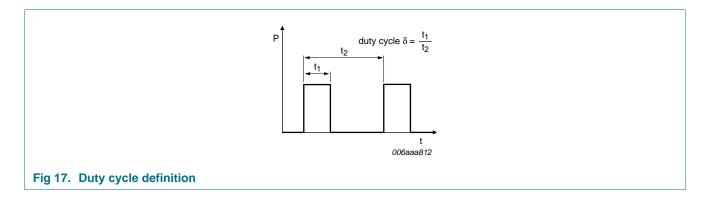
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8. Test information



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9. Package outline

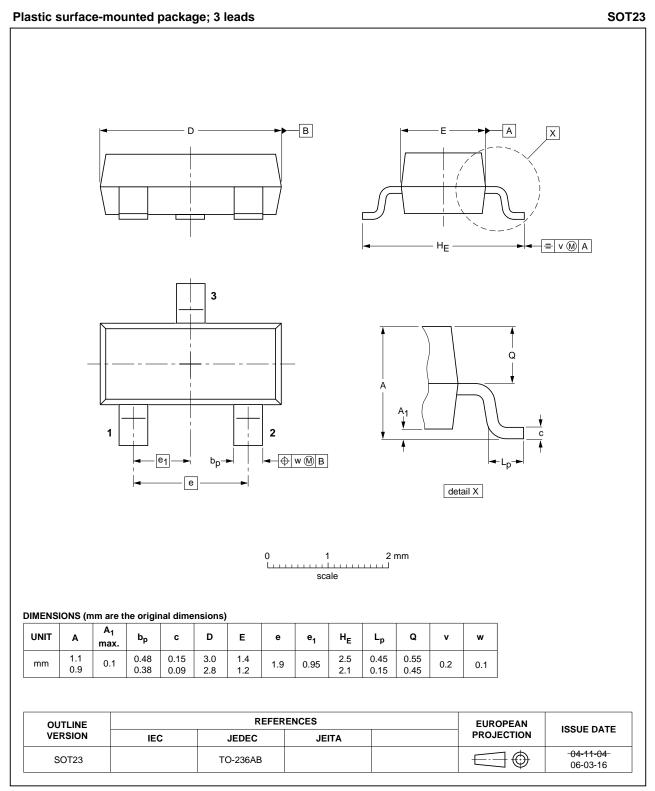
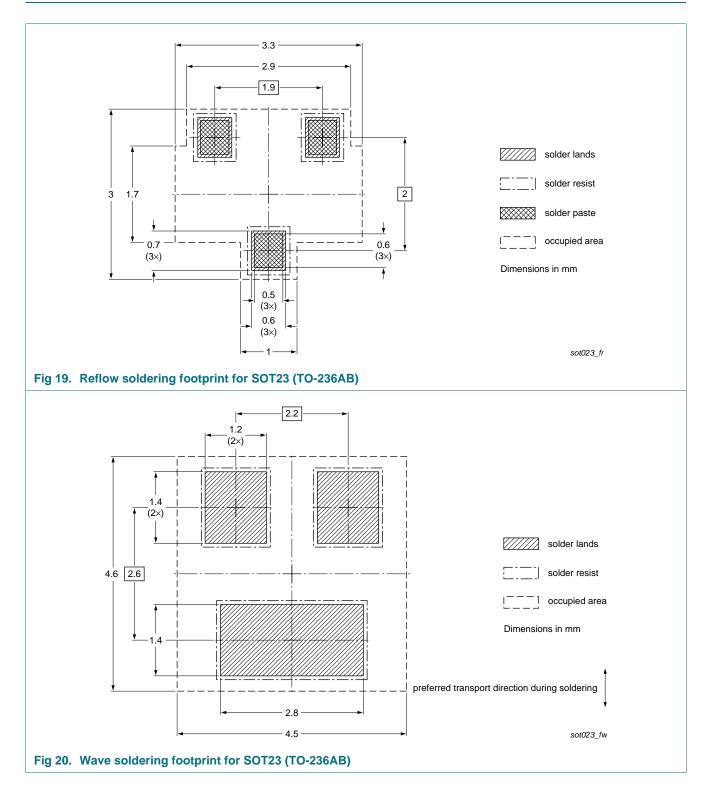


Fig 18. Package outline SOT23 (TO-236AB)

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10. Soldering



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11. Revision history

Table 8.Revision	n history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMV160UP v.2	20111206	Product data sheet	-	PMV160UP v.1
Modifications:	• 7 "Character	istics": V _{GSth} condition is corr	ected	
PMV160UP v.1	20110907	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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